

# CPC COOPERATIVE PATENT CLASSIFICATION

## H ELECTRICITY

(NOTE omitted)

## H01 ELECTRIC ELEMENTS

(NOTES omitted)

## H01C RESISTORS

### NOTES

1. In this subclass, the term "adjustable" means mechanically adjustable.
2. Variable resistors, the value of which is changed non-mechanically, e.g. by voltage or temperature, are classified in group [H01C 7/00](#).

### WARNING

In this subclass non-limiting references (in the sense of paragraph 39 of the Guide to the IPC) may still be displayed in the scheme.

<b>1/00</b>	<b>Details</b>	1/14	• Terminals or tapping points specially adapted for resistors; Arrangements of terminals or tapping points on resistors
1/01	• Mounting; Supporting	1/1406	• • {Terminals or electrodes formed on resistive elements having positive temperature coefficient}
1/012	• • the base extending along and imparting rigidity or reinforcement to the resistive element ( <a href="#">H01C 1/016 takes precedence</a> ; the resistive element being formed in two or more coils or loops as a spiral, helical or toroidal winding <a href="#">H01C 3/18</a> , <a href="#">H01C 3/20</a> ; the resistive element being formed as one or more layers or coatings on a base <a href="#">H01C 7/00</a> )	1/1413	• • {Terminals or electrodes formed on resistive elements having negative temperature coefficient}
1/014	• • the resistor being suspended between and being supported by two supporting sections ( <a href="#">H01C 1/016 takes precedence</a> )	1/142	• • the terminals or tapping points being coated on the resistive element
1/016	• • with compensation for resistor expansion or contraction	1/144	• • the terminals or tapping points being welded or soldered
1/02	• Housing; Enclosing; Embedding; Filling the housing or enclosure	1/146	• • the resistive element surrounding the terminal
1/022	• • the housing or enclosure being openable or separable from the resistive element	1/148	• • the terminals embracing or surrounding the resistive element ( <a href="#">H01C 1/142 takes precedence</a> )
1/024	• • the housing or enclosure being hermetically sealed ( <a href="#">H01C 1/028</a> , <a href="#">H01C 1/032</a> , <a href="#">H01C 1/034 take precedence</a> )	1/16	• Resistor networks not otherwise provided for
1/026	• • • with gaseous or vacuum spacing between the resistive element and the housing or casing	<b>3/00</b>	<b>Non-adjustable metal resistors made of wire or ribbon, e.g. coiled, woven or formed as grids</b>
1/028	• • the resistive element being embedded in insulation with outer enclosing sheath	3/005	• {Metallic glasses therefor}
1/03	• • • with powdered insulation	3/02	• arranged or constructed for reducing self-induction, capacitance or variation with frequency
1/032	• • plural layers surrounding the resistive element ( <a href="#">H01C 1/028 takes precedence</a> )	3/04	• Iron-filament ballast resistors; Other resistors having variable temperature coefficient
1/034	• • the housing or enclosure being formed as coating or mould without outer sheath ( <a href="#">H01C 1/032 takes precedence</a> )	3/06	• Flexible or folding resistors, whereby such a resistor can be looped or collapsed upon itself
1/036	• • • on wound resistive element	3/08	• Dimension or characteristic of resistive element changing gradually or in discrete steps from one terminal to another
1/04	• Arrangements of distinguishing marks, e.g. colour coding	3/10	• the resistive element having zig-zag or sinusoidal configuration
1/06	• Electrostatic or electromagnetic shielding arrangements	3/12	• • lying in one plane
1/08	• Cooling, heating or ventilating arrangements	3/14	• the resistive element being formed in two or more coils or loops continuously wound as a spiral, helical or toroidal winding ( <a href="#">H01C 3/02 - H01C 3/12 take precedence</a> )
1/082	• • using forced fluid flow	3/16	• • including two or more distinct wound elements or two or more winding patterns
1/084	• • using self-cooling, e.g. fins, heat sinks	3/18	• • wound on a flat or ribbon base ( <a href="#">H01C 3/16 takes precedence</a> )
1/12	• Arrangements of current collectors	3/20	• • wound on cylindrical or prismatic base ( <a href="#">H01C 3/16 takes precedence</a> )
1/125	• • of fluid contacts		

<b>7/00</b>	<b>Non-adjustable resistors formed as one or more layers or coatings; Non-adjustable resistors made from powdered conducting material or powdered semi-conducting material with or without insulating material (consisting of loose powdered or granular material <a href="#">H01C 8/00</a>; resistors having potential barriers, e.g. field-effect resistors, <a href="#">H10D 1/40</a> - <a href="#">H10D 1/43</a>, <a href="#">H10K 10/10</a>; semiconductor devices sensitive to electromagnetic or corpuscular radiation, e.g. photoresistors, <a href="#">H10F 30/00</a>; magnetic field controlled resistors <a href="#">H10N 50/10</a>; bulk negative resistance effect devices <a href="#">H10N 80/00</a>)</b>	7/12	. . . Overvoltage protection resistors; Arresters
7/001	. {Mass resistors}	7/123	. . . {Arrangements for improving potential distribution}
7/003	. {Thick film resistors}	7/126	. . . {Means for protecting against excessive pressure or for disconnecting in case of failure}
7/005	. . {Polymer thick films}	7/13	. current-responsive
7/006	. {Thin film resistors}		
7/008	. {Thermistors ( <a href="#">H01C 7/02</a> - <a href="#">H01C 7/06</a> take precedence)}	<b>NOTE</b>	
7/02	. having positive temperature coefficient		Groups <a href="#">H01C 7/02</a> - <a href="#">H01C 7/13</a> take precedence over groups <a href="#">H01C 7/18</a> - <a href="#">H01C 7/22</a> .
7/021	. . {formed with two or more layers}	7/18	. comprising a plurality of layers stacked between terminals
7/022	. . {mainly consisting of non-metallic substances ( <a href="#">H01C 7/021</a> takes precedence)}	7/20	. the resistive layer or coating being tapered
7/023	. . . {containing oxides or oxidic compounds, e.g. ferrites}	7/22	. Elongated resistive element being bent or curved, e.g. sinusoidal, helical
7/025	. . . . {Perovskites, e.g. titanates}	<b>8/00</b>	<b>Non-adjustable resistors consisting of loose powdered or granular conducting, or powdered or granular semi-conducting material</b>
7/026	. . . . {Vanadium oxides or oxidic compounds, e.g. VO <sub>x</sub> }	8/02	. Cohereers or like imperfect resistors for detecting electromagnetic waves
7/027	. . {consisting of conducting or semi-conducting material dispersed in a non-conductive organic material}	8/04	. Overvoltage protection resistors; Arresters
7/028	. . {consisting of organic substances}	<b>10/00</b>	<b>Adjustable resistors</b>
7/04	. having negative temperature coefficient	10/005	. {Surface mountable, e.g. chip trimmer potentiometer}
	<b>NOTE</b>	10/02	. Liquid resistors
	{In groups <a href="#">H01C 7/043</a> - <a href="#">H01C 7/049</a> , the last place priority rule is applied, i.e. at each hierarchical level, in the absence of an indication to the contrary, classification is made in the last appropriate place.}	10/025	. . {Electrochemical variable resistors ( <a href="#">trimming resistors by electrolytic treatment</a> <a href="#">H01C 17/2412</a> , <a href="#">H01C 17/262</a> )}
7/041	. . {formed with two or more layers}	10/04	. with specified mathematical relationship between movement of resistor actuating means and value of resistance, other than direct proportional relationship
7/042	. . {mainly consisting of inorganic non-metallic substances ( <a href="#">H01C 7/041</a> takes precedence)}	10/06	. adjustable by short-circuiting different amounts of the resistive element
7/043	. . . {Oxides or oxidic compounds}	10/08	. . with intervening conducting structure between the resistive element and the short-circuiting means, e.g. taps
7/044	. . . . {Zinc or cadmium oxide}	10/10	. adjustable by mechanical pressure or force
7/045	. . . . {Perovskites, e.g. titanates}	10/103	. . {by using means responding to magnetic or electric fields, e.g. by addition of magnetisable or piezoelectric particles to the resistive material, or by an electromagnetic actuator}
7/046	. . . . {Iron oxides or ferrites}	10/106	. . {on resistive material dispersed in an elastic material ( <a href="#">H01C 10/103</a> and <a href="#">H01C 10/12</a> take precedence; for electric switches <a href="#">H01H 1/029</a> )}
7/047	. . . . {Vanadium oxides or oxidic compounds, e.g. VO <sub>x</sub> }	10/12	. . by changing surface pressure between resistive masses or resistive and conductive masses, e.g. pile type
7/048	. . . {Carbon or carbides}	10/14	. adjustable by auxiliary driving means
7/049	. . {mainly consisting of organic or organo-metal substances}	10/16	. including plural resistive elements
7/06	. including means to minimise changes in resistance with changes in temperature	10/18	. . including coarse and fine resistive elements
7/10	. voltage responsive, i.e. varistors	10/20	. . Contact structure or movable resistive elements being ganged
7/1006	. . {Thick film varistors}	10/22	. resistive element dimensions changing gradually in one direction, e.g. tapered resistive element ( <a href="#">H01C 10/04</a> takes precedence)
7/1013	. . {Thin film varistors}	10/23	. resistive element dimensions changing in a series of discrete, progressive steps
7/102	. . Varistor boundary, e.g. surface layers ( <a href="#">H01C 7/12</a> takes precedence)	10/24	. the contact moving along turns of a helical resistive element, or vice versa
7/105	. . Varistor cores ( <a href="#">H01C 7/12</a> takes precedence)		
7/108	. . . Metal oxide		
7/112	. . . . ZnO type		
7/115	. . . . Titanium dioxide- or titanate type		
7/118	. . . Carbide, e.g. SiC type		

- 10/26 . . resistive element moving ([H01C 10/16](#), [H01C 10/24](#) take precedence)
- NOTE**
- Groups [H01C 10/02](#) - [H01C 10/26](#) take precedence over groups [H01C 10/28](#) - [H01C 10/50](#).
- 10/28 . . the contact rocking or rolling along resistive element or taps
- 10/30 . . the contact sliding along resistive element
- 10/301 . . {consisting of a wire wound resistor}
- 10/303 . . . {the resistor being coated, e.g. lubricated, conductive plastic coated, i.e. hybrid potentiometer}
- 10/305 . . {consisting of a thick film}
- 10/306 . . . {Polymer thick film, i.e. PTF}
- 10/308 . . {consisting of a thin film}
- 10/32 . . the contact moving in an arcuate path
- 10/34 . . . the contact or the associated conducting structure riding on collector formed as a ring or portion thereof
- 10/345 . . . . {the collector and resistive track being situated in 2 parallel planes}
- 10/36 . . . structurally combined with switching arrangements
- 10/363 . . . . {by axial movement of the spindle, e.g. pull-push switch ([H01C 10/366](#) takes precedence)}
- 10/366 . . . . {using an electromagnetic actuator}
- 10/38 . . the contact moving along a straight path
- 10/40 . . . screw operated
- 10/42 . . . . the contact bridging and sliding along resistive element and parallel conducting bar or collector
- 10/44 . . . the contact bridging and sliding along resistive element and parallel conducting bar or collector ([H01C 10/42](#) takes precedence)
- 10/46 . . Arrangements of fixed resistors with intervening connectors, e.g. taps ([H01C 10/28](#), [H01C 10/30](#) take precedence)
- 10/48 . . including contact movable in an arcuate path
- 10/50 . . structurally combined with switching arrangements ([H01C 10/36](#) takes precedence)
- 11/00 Non-adjustable liquid resistors**
- 13/00 Resistors not provided for elsewhere**
- 13/02 . . Structural combinations of resistors
- 17/00 Apparatus or processes specially adapted for manufacturing resistors (providing fillings for housings or enclosures [H01C 1/02](#); reducing insulation surrounding a resistor to powder [H01C 1/03](#); manufacture of thermally variable resistors [H01C 7/02](#), [H01C 7/04](#))**
- 17/003 . . {using lithography, e.g. photolithography (lithographic compositions and processing in general [G03F](#))}
- 17/006 . . {adapted for manufacturing resistor chips}
- 17/02 . . adapted for manufacturing resistors with envelope or housing (apparatus or processes for filling or compressing insulating material in heating element tubes [H05B 3/52](#))
- 17/04 . . adapted for winding the resistive element
- 17/06 . . adapted for coating resistive material on a base
- 17/065 . . . by thick film techniques, e.g. serigraphy
- 17/06506 . . . . {Precursor compositions therefor, e.g. pastes, inks, glass frits or green body}
- 17/06513 . . . . . {characterised by the resistive component}
- 17/0652 . . . . . {containing carbon or carbides}
- 17/06526 . . . . . {composed of metals}
- 17/06533 . . . . . {composed of oxides}
- 17/0654 . . . . . {Oxides of the platinum group}
- 17/06546 . . . . . {Oxides of zinc or cadmium}
- 17/06553 . . . . . {composed of a combination of metals and oxides}
- 17/0656 . . . . . {composed of silicides ([H01C 17/0652](#) takes precedence)}
- 17/06566 . . . . . {composed of borides ([H01C 17/0652](#) takes precedence)}
- 17/06573 . . . . . {characterised by the permanent binder}
- 17/0658 . . . . . {composed of inorganic material}
- 17/06586 . . . . . {composed of organic material}
- 17/06593 . . . . . {characterised by the temporary binder}
- 17/07 . . by resistor foil bonding, e.g. cladding
- 17/075 . . by thin-film techniques
- 17/08 . . by vapour deposition
- 17/10 . . by flame spraying
- 17/12 . . by sputtering
- 17/14 . . by chemical deposition
- 17/16 . . . . using electric current
- 17/18 . . . . without using electric current
- 17/20 . . by pyrolytic processes
- 17/22 . . adapted for trimming
- 17/23 . . by opening or closing resistor geometric tracks of predetermined resistive values, {e.g. snapistors}
- 17/232 . . Adjusting the temperature coefficient; Adjusting value of resistance by adjusting temperature coefficient of resistance
- 17/235 . . Initial adjustment of potentiometer parts for calibration
- 17/24 . . by removing or adding resistive material ([H01C 17/23](#), [H01C 17/232](#), [H01C 17/235](#) take precedence)
- 17/2404 . . . {by charged particle impact, e.g. by electron or ion beam milling, sputtering, plasma etching}
- 17/2408 . . . {by pulsed voltage erosion, e.g. spark erosion}
- 17/2412 . . . {by electrolytic treatment, e.g. electroplating (for anodic oxydation [H01C 17/262](#))}
- 17/2416 . . . {by chemical etching}
- 17/242 . . . by laser
- 17/245 . . . by mechanical means, e.g. sand-blasting, cutting or ultrasonic treatment
- 17/26 . . by converting resistive material
- 17/262 . . . {by electrolytic treatment, e.g. anodic oxydation}
- 17/265 . . . {by chemical or thermal treatment, e.g. oxydation, reduction, annealing ([etching H01C 17/2416](#))}
- 17/267 . . . . {by passage of voltage pulses or electric current}
- 17/28 . . adapted for applying terminals
- 17/281 . . {by thick film techniques}
- 17/283 . . . {Precursor compositions therefor, e.g. pastes, inks, glass frits}
- 17/285 . . . . {applied to zinc or cadmium oxide resistors}
- 17/286 . . . . {applied to TiO<sub>2</sub> or titanate resistors}
- 17/288 . . {by thin film techniques}

17/30 . adapted for baking